## TELANGANA UNIVERSITY S.S.R. DEGREE COLLEGE, NIZAMABAD (C.C:5029) VI SEMESTER INTERNAL ASSESSMENT II EXAMINATIONS

## PHYSICS (ELECTRONICS) QUESTION BANK

I. Choose the correct	Answers.			F1 3
1. In an SCR	/b\ III > II	/o/ II > III	(d) Both a and h	[b]
(a) IH < IL	(b) IH > IL	(c) IL > IH	(d) Both a and b	
2. An SCR can be brouexceeds.	ught to forward conductir	ng state with gate-circuit open w	hen the applied voltage	e [a]
(a) The forward break (c) 1.5 V	cover voltage	• •	<ul><li>(b) Reverse breakdown voltage</li><li>(d) Peak non-repetitive off-state voltage</li></ul>	
3. The di/dt rating of (a) Decaying anode cu (c) Rising gate current		(b) Decaying gate converted (d) Rising anode current	r	[d]
<ul><li>4. Which of the follow</li><li>(a) High current</li><li>(c) High temperature</li></ul>		anent damage of an SCR? (b) High rate of rise of curre (d) High rate of rise of volta		[a]
5. UJT is generally use (a) Square wave gene (c) Sawtooth wave ge	ration	<ul><li>(b) Triangle wave generation</li><li>(d) Sine wave generation</li></ul>	on	[c]
6. FET acts as voltage (a) Cutoff	variable resistor at (b) Saturation	region. (c) Ohmic	(d) None	[c]
7. Solar cell is a type (a) Photo-conductive (c) Photo-voltaic devi	device	(b) Photo-emissive device (d) Electromotive device		[c]
8. A photo diode is (a) A photo detector (c) Encased in opaque		(b) Operated in forward dir (d) None of the above	ection	[a]
9. The current flowing (a) More (C) Dark current	g through a photo diode v	vhen there is no light is (b) Breakdown circuit (d) Hole current		[c]
10. An LED can be ma (a) Germanium (c) Gallium Arsenide	de from	(b) Silicon (d) Phosphorescent materia	al	[c]
11. 1's complement of (a) 1110	of 0000 is, (b) 1111	(c) 0100	(d) 1100	[b]
12. The binary number (a) 0 (or) 1	er is represented by (b) only '1'	(c) only '0'	(d) 0 (and) 1	[d]

13. (10110111)2 = ( ) <sub>10</sub>	W. V		[b]	
(a) 133	(b) 183	(c) 152	(d) 188	
14 and are the only two possible values in coefficient of binary number system				
(a) 0	(b) 1	(c) Both a & b	(d) None	
15. 2's complement of the nu	umber 1001 is		[c]	
(a) 0110	(b) 0001	(c) 0111	(d) 0101	
16. The functions of AND gate with bubbles on input is sames asgate				
(a) AND	(b) NOR	(c) XOR	(d) NOT	
17. NAND gate is AND gate for	ollowed by gate		[a]	
(a) NOT	(b) OR	(c) AND	(d) NOR	
18. According to Demorgan's	s theorem $\overline{A+B}$ =		[a]	
(a) $\overline{A}.\overline{B}$	(b) AB	(c) A + B	(d) $\overline{A} + \overline{B}$	
19. Which of the following is th	e alternative symbol for NOR?		[d]	
-		•		
		-	•	
(a)		(b)		
		. 5		
			-	
(c)		(d)		
	-	(u)		
20. The universal gate is (a) NAND	(b) AND	(c) NOT	[a]	
	· <i>,</i>	•	` ,	

- II. Fill in the Blanks
- 1. When forward voltage is applied to SCR, its gate recovery time increases
- 2. The V-I characteristics of SCR is also known as <a href="Static anode-cathode">Static anode-cathode</a> characteristics.
- 3. Shockley diode is a four layer PNPN silicon device
- 4. The UJT is operated as oscillator in negative resistance region.
- 5. In UJT, the resistivity of <u>base</u> terminal is very high.
- 6. FET acts as Voltage Variable Resistor under which drain resistance (r) varies with VGS
- 7. In photo diode, light signals are converted into electrical signals.
- 8. The dark current in photo diode is due to thermally generated minority carriers
- 9. LED emits light
- 10. Opto-coupler is also called opto isolator since it provides electrical isolation between any two circuits.
- 11. NOR gate is OR gate followed by NOT gate.
- 12. The binary number 10101 is equivalent to decimal number 21
- 13. Decimal number 10 is equal to binary number 1010
- 14. A binary number system employs base 2 system.
- 15. A binary digit is called as bit
- 16. 1's complement of the number 0111 is 1000
- 17. The function of AND gate with bubbles on its inputs is same as NOR gate
- 18. According to De-Morgan's theorem,  $\overline{AB} = \overline{A} + \overline{B}$
- 19. NAND and NOR gates are called universal gates
- 20. A <u>number</u> system is a combination of digits or numbers.

- III. Short Answers.
- 1. Why FET is called as "voltage operated device"?

A: PET is called as voltage controlled device as, gate-source voltage i.e V<sub>GS</sub>, controls drain current, I<sub>D</sub>

2. Define dark current in photodiode?

A: Dark current is a very small current that appears in reverse bias of photodiode i.e when no light is applied.

3. Define holding current of SCR?

A: The minimum value of anode current required to keep the SCR ON is called as holding current.

4. What is negative resistance region of UJT?

A: The region existing between the peak point and valley point is referred as negative resistance region of UJT.

5. What is a LED?

A: Light emitting diode is a PN junction diode which emits light in forward biased region.

6. What is binary number system?

A: A system that represents a number with only two digits i.e., 0 and 1 is known as binary system.

7. What is Hexadecimal number system?

A: A system that represents a number with the combination of 16 digits i.e., 0,1,2,3,4,5,6,7,8,9, A, B,C,D,E and F is known as Hexadecimal number system.

8. How one's complement is represented?

A: A binary number can be represented in one's complement form by simply replacing 1 with 0 and 0 with 1. For example, the one's complement of binary number 11010 is 00101.

9. What is a logic gate?

A: Logic gate is the basic element that builds a digital system to perform logical function.

10. What are the basic digital logic gates?

A: The three basic digital logic gates are 1) AND gate 2) OR gate 3) NOT gate